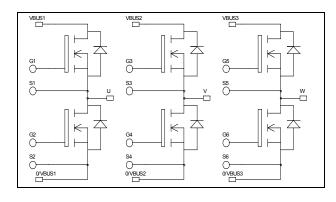


Triple phase leg MOSFET Power Module



$$\begin{split} V_{DSS} &= 1000 V \\ R_{DSon} &= 350 m \Omega \text{ typ } \text{ } \text{ } \text{ } \text{Tj} = 25^{\circ} \text{C} \\ I_D &= 22 \text{A} \text{ } \text{ } \text{ } \text{ } \text{Tc} = 25^{\circ} \text{C} \end{split}$$

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Very low (12mm) profile
- Each leg can be easily paralleled to achieve a phase leg of three times the current capability
- Module can be configured as a three phase bridge
- Module can be configured as a boost followed by a full bridge
- RoHS Compliant

Absolute	maximum	ratings

Mo/∨BUS1

MO/VBUS2

0/VBUS3

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		1000	V
Ţ	$T_c = 25^{\circ}C$		22	
I_{D}	Continuous Drain Current	$T_c = 80$ °C	17	A
I_{DM}	Pulsed Drain current		88	
V_{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		420	mΩ
P_{D}	Maximum Power Dissipation $T_c = 25^{\circ}C$		390	W
I_{AR}	Avalanche current (repetitive and non repetitive)		25	A
E_{AR}	Repetitive Avalanche Energy		50	m I
E_{AS}	Single Pulse Avalanche Energy		3000	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

APTM100TA35FPG-Rev 2 October 2012



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 25^{\circ}C$			100	μА
		$V_{GS} = 0V, V_{DS} = 800V$	$T_j = 125$ °C			500	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 11A$			350	420	mΩ
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 2.5 \text{mA}$		3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$				±100	nA

Dynamic Characteristics

•	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		5.2		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		0.88		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		0.16		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		186		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 500V$		24		nC
$Q_{gd} \\$	Gate – Drain Charge	$I_D = 22A$		122		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C $V_{GS} = 15V$ $V_{Bus} = 670V$ $I_D = 22A$ $R_G = 5\Omega$		18		
$T_{\rm r}$	Rise Time			12		
$T_{d(off)}$	Turn-off Delay Time			155		ns
T_{f}	Fall Time			40		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$, $V_{Bus} = 670V$ $I_D = 22A$, $R_G = 5\Omega$		900		
E _{off}	Turn-off Switching Energy			623		μJ
E_{on}	Turn-on Switching Energy	Inductive switching @ 125°C		1423		
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 22A, R_G = 5\Omega$		779		μJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$			22	٨
	(Body diode)		$Tc = 80^{\circ}C$			17	A
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -22A$				1.3	V
dv/dt	Peak Diode Recovery					18	V/ns
+	Payarga Pagayary Tima		$T_j = 25^{\circ}C$			320	na
t _{rr}	Reverse Recovery Time	$I_S = -22A$ $V_R = 670V$	$T_j = 125$ °C			650	ns
0	Davarga Dagayary Charga	$di_{S}/dt = 100A/\mu s$	$T_j = 25$ °C		3.6		C
Qrr	Reverse Recovery Charge	323, 321 2 0 0 1 2 µ 0	$T_j = 125$ °C		9.72		μC

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

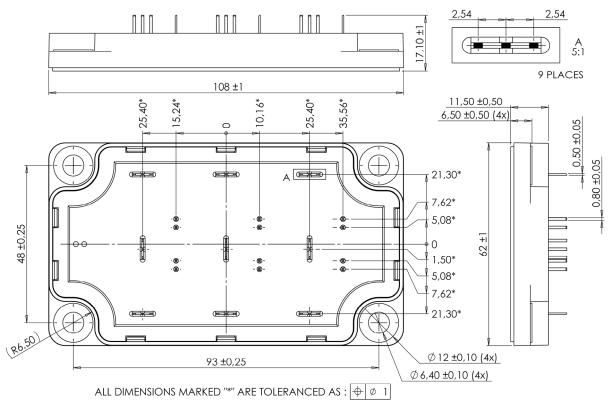
 $I_S \le$ - 22A $di/dt \le 700 A/\mu s$ $V_R \le V_{DSS}$ $T_j \le 150^{\circ} C$



Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance	Junction to Case Thermal Resistance				0.32	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
$T_{\rm J}$	Operating junction temperature range		-40		150		
T _{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight					250	g

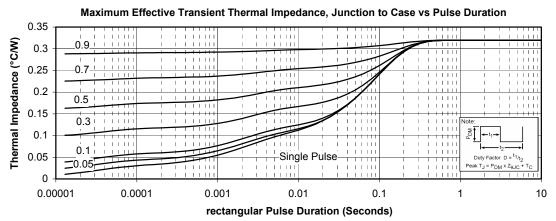
SP6-P Package outline (dimensions in mm)

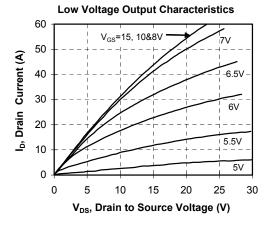


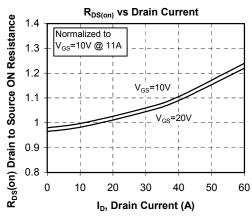
See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com

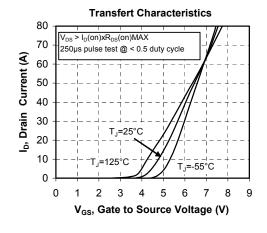


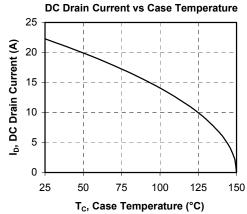
Typical Performance Curve



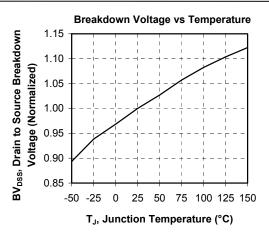


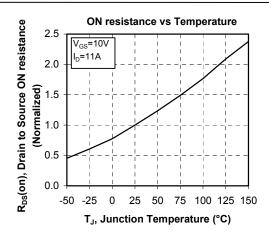


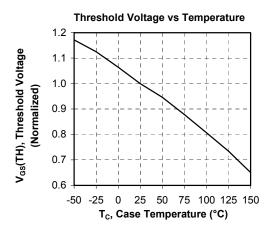


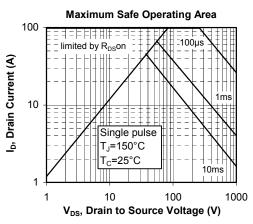


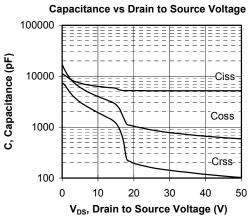


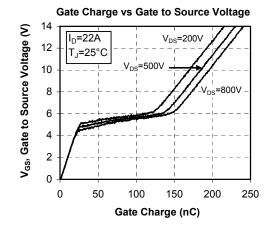




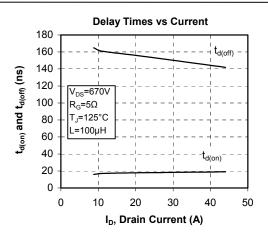


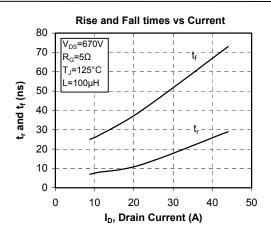


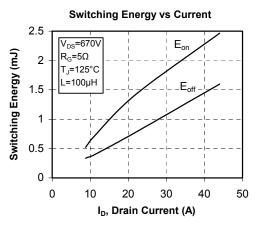


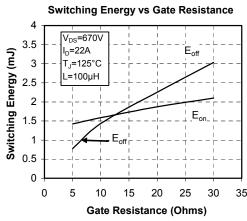


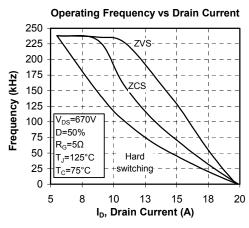


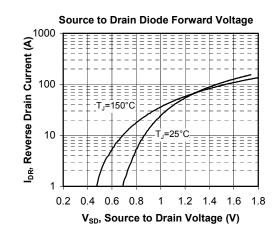














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APTM100TA35FPG-Rev 2 October 2012